MM54C922/MM74C922 16-Key Encoder MM54C923/MM74C923 20-Key Encoder

General Description

These CMOS key encoders provide all the necessary logic to fully encode an array of SPST switches. The keyboard scan can be implemented by either an external clock or external capacitor. These encoders also have on-chip pull-up devices which permit switches with up to $50~\mathrm{k}\Omega$ on resistance to be used. No diodes in the switch array are needed to eliminate ghost switches. The internal debounce circuit needs only a single external capacitor and can be defeated by omitting the capacitor. A Data Available output goes to a high level when a valid keyboard entry has been made. The Data Available output returns to a low level when the entered key is released, even if another key is depressed. The Data Available will return high to indicate acceptance of the new key after a normal debounce period; this two-key rollover is provided between any two switches.

An internal register remembers the last key pressed even after the key is released. The TRI-STATE® outputs provide for easy expansion and bus operation and are LPTTL compatible.

Features

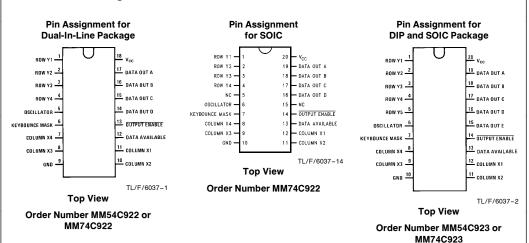
- 50 k Ω maximum switch on resistance
- On or off chip clock
- On-chip row pull-up devices
- 2 key roll-over
- Keybounce elimination with single capacitor
- Last key register at outputs
- TRI-STATE outpust LPTTL compatible
- Wide supply range

3V to 15V

MM54C922/MM74C922 16-Key Encoder, MM54C923/MM74C923 20-Key Encodeı

■ Low power consumption

Connection Diagrams



TRI-STATE® is a registered trademark of National Semiconductor Corporation

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

 $V_{\hbox{\footnotesize CC}}-$ 0.3V to $V_{\hbox{\footnotesize CC}}+$ 0.3V Voltage at Any Pin Operating Temperature Range MM54C922, MM54C923

-55°C to +125°C -40°C to +85°C MM74C922, MM74C923

Storage Temperature Range -65°C to $+150^{\circ}\text{C}$

Power Dissipation (PD) Dual-In-Line

700 mW 500 mW 3V to 15V 18V

 V_{CC} Lead Temperature

Small Outline

Operating V_{CC} Range

260°C (Soldering, 10 seconds)

DC Electrical Characteristics Min/Max limits apply across temperature range unless otherwise specified

			T	_	T	
Symbol	Parameter	Conditions	Min	Тур	Max	Units
CMOS TO	CMOS					
V_{T+}	Positive-Going Threshold Voltage	$V_{CC} = 5V$, $I_{IN} \ge 0.7$ mA	3.0	3.6	4.3	V
	at Osc and KBM Inputs	$V_{CC} = 10V, I_{IN} \ge 1.4 \text{ mA}$	6.0	6.8	8.6	V
		$V_{CC} = 15V, I_{IN} \ge 2.1 \text{ mA}$	9.0	10	12.9	V
V_{T-}	Negative-Going Threshold Voltage	$V_{CC} = 5V$, $I_{IN} \ge 0.7$ mA	0.7	1.4	2.0	V
	at Osc and KBM Inputs	$V_{CC} = 10V$, $I_{IN} \ge 1.4$ mA	1.4	3.2	4.0	V
		$V_{CC} = 15V, I_{IN} \ge 2.1 \text{ mA}$	2.1	5	6.0	V
$V_{IN(1)}$	Logical "1" Input Voltage,	$V_{CC} = 5V$	3.5	4.5		V
	Except Osc and KBM Inputs	$V_{CC} = 10V$	8.0	9		V
		$V_{CC} = 15V$	12.5	13.5		V
V _{IN(0)}	Logical "0" Input Voltage,	$V_{CC} = 5V$		0.5	1.5	V
(-)	Except Osc and KBM Inputs	V _{CC} = 10V		1	2	V
		$V_{CC} = 15V$		1.5	2.5	V
I _{rp}	Row Pull-Up Current at Y1, Y2,	$V_{CC} = 5V, V_{IN} = 0.1 V_{CC}$		-2	-5	μΑ
16	Y3, Y4 and Y5 Inputs	V _{CC} = 10V		-10	-20	μA
		V _{CC} = 15V		-22	-45	μA
V _{OUT(1)}	Logical "1" Output Voltage	$V_{CC} = 5V, I_{O} = -10 \mu A$	4.5			V
001(1)		$V_{CC} = 10V, I_{O} = -10 \mu A$	9			V
		$V_{CC} = 15V, I_{O} = -10 \mu A$	13.5			V
V _{OUT(0)}	Logical "0" Output Voltage	$V_{CC} = 5V, I_{C} = 10 \mu A$			0.5	V
001(0)		$V_{CC} = 10V, I_{O} = 10 \mu A$			1	V
		$V_{CC} = 15V, I_{O} = 10 \mu A$			1.5	V
Ron	Column "ON" Resistance at	$V_{CC} = 5V, V_{C} = 0.5V$		500	1400	Ω
OII	X1, X2, X3 and X4 Outputs	$V_{CC} = 10V, V_{C} = 1V$		300	700	Ω
		$V_{CC} = 15V, V_{O} = 1.5V$		200	500	Ω
Icc	Supply Current	$V_{CC} = 5V$		0.55	1.1	mA
-00	Osc at 0V, (one Y low)	$V_{CC} = 10V$		1.1	1.9	mA
		V _{CC} = 15V		1.7	2.6	mA
I _{IN(1)}	Logical "1" Input Current	V _{CC} = 15V, V _{IN} = 15V				_
-114(1)	at Output Enable	100 111, 111		0.005	1.0	μΑ
I _{IN(0)}	Logical "0" Input Current	$V_{CC} = 15V, V_{IN} = 0V$				
יווי(ט)	at Output Enable	100, 1N	-1.0	-0.005		μΑ
CMOS/LE	PTTL INTERFACE		1			
	I	54C V - 45V	\/ 1.F			V
$V_{IN(1)}$	Logical "1" Input Voltage, Except Osc and KBM Inputs	$54C, V_{CC} = 4.5V$	V _{CC} - 1.5 V _{CC} - 1.5			V
.,		74C, V _{CC} = 4.75V	ACC - 1.2		0.0	
$V_{IN(0)}$	Logical "0" Input Voltage,	54C, V _{CC} = 4.5V			0.8	V
	Except Osc and KBM Inputs	$74C, V_{CC} = 4.75V$			0.8	V
$V_{OUT(1)}$	Logical "1" Output Voltage	54C, V _{CC} = 4.5V	2.4			V
		$I_{O} = -360 \mu\text{A}$				
		$74C, V_{CC} = 4.75V$	2.4			V
.,		$I_0 = -360 \mu\text{A}$				
$V_{OUT(0)}$	Logical "0" Output Voltage	54C, V _{CC} = 4.5V			0.4	V
		$I_0 = -360 \mu\text{A}$				
		74C, V _{CC} = 4.75V			0.4	V
		$I_{O} = -360 \mu\text{A}$	1		l	l

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

DC Electrical Characteristics

Min/Max limits apply across temperature range unless otherwise specified (Continued)

Symbol	Parameter	Conditions	Min	Тур	Max	Units						
OUTPUT DRIVE (See 54C/74C Family Characteristics Data Sheet) (Short Circuit Current)												
ISOURCE	Output Source Current (P-Channel)	$V_{CC} = 5V$, $V_{OUT} = 0V$, $T_A = 25$ °C	−1.75	-3.3		mA						
ISOURCE	Output Source Current (P-Channel)	$V_{CC} = 10V, V_{OUT} = 0V, T_A = 25^{\circ}C$	-8	-15		mA						
I _{SINK}	Output Sink Current (N-Channel)	$V_{CC} = 5V$, $V_{OUT} = V_{CC}$, $T_A = 25^{\circ}C$	1.75	3.6		mA						
I _{SINK}	Output Sink Current (N-Channel)	$V_{CC} = 10V, V_{OUT} = V_{CC},$ $T_A = 25^{\circ}C$	8	16		mA						

AC Electrical Characteristics* $T_A = 25^{\circ}C, C_L = 50 \text{ pF}, \text{ unless otherwise noted}$

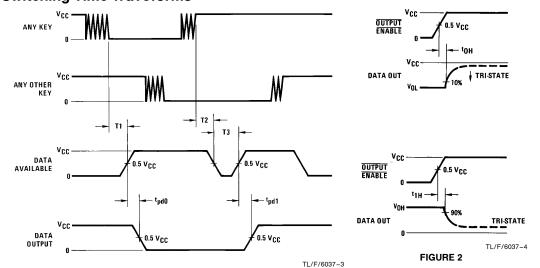
Symbol	Parameter	Conditions	Min	Тур	Max	Units	
t _{pd0} , t _{pd1}	Propagation Delay Time to Logical "0" or Logical "1" from D.A.	C _L = 50 pF (Figure 1) V _{CC} = 5V V _{CC} = 10V V _{CC} = 15V		60 35 25	150 80 60	ns ns ns	
t _{0H} , t _{1H}	Propagation Delay Time from Logical "0" or Logical "1" into High Impedance State	R _L = 10k, C _L = 10 pF (Figure 2) V _{CC} = 5V, R _L = 10k V _{CC} = 10V, C _L = 10 pF V _{CC} = 15V		80 65 50	200 150 110	ns ns ns	
t _{H0} , t _{H1}	Propagation Delay Time from High Impedance State to a Logical "0" or Logical "1"	$\begin{aligned} & R_L = 10 \text{k, } C_L = 50 \text{ pF } \textit{(Figure 2)} \\ & V_{CC} = 5 \text{V, } R_L = 10 \text{k} \\ & V_{CC} = 10 \text{V, } C_L = 50 \text{ pF} \\ & V_{CC} = 15 \text{V} \end{aligned}$		100 55 40	250 125 90	ns ns ns	
C _{IN}	Input Capacitance	Any Input (Note 2)		5	7.5	pF	
C _{OUT}	TRI-STATE Output Capacitance	Any Output (Note 2)		10		pF	

^{*}AC Parameters are guaranteed by DC correlated testing.

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

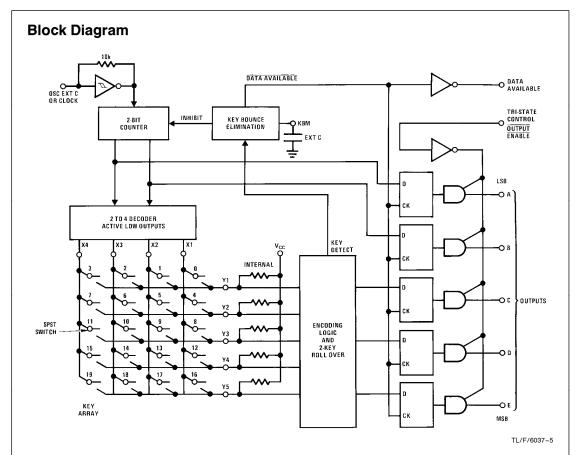
Note 2: Capacitance is guaranteed by periodic testing.

Switching Time Waveforms



T1 \approx T2 \approx RC, T3 \approx 0.7 RC, where R \approx 10k and C is external capacitor at KBM input.

FIGURE 1

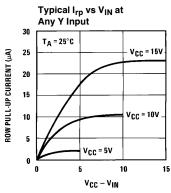


Truth Table

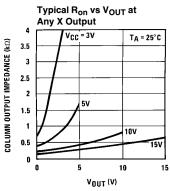
Swi	tch	0	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19
Posi	tion	Y1,X1	Y1,X2	Y1,X3	Y1,X4	Y2,X1	Y2,X2	Y2,X3	Y2,X4	Y3,X1	Y3,X2	Y3,X3	Y3,X4	Y4,X1	Y4,X2	Y4,X3	Y4,X4	Y5*,X1	Y5*,X2	Y5*,X3	Y5*,X4
D																					
Α	Α	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1
Т	В	0	0	1	1	0	0	1	1	0	0	1	1	0	0	1	1	0	0	1	1
Α	С	0	0	0	0	1	1	1	1	0	0	0	0	1	1	1	1	0	0	0	0
0	D	0	0	0	0	0	0	0	0	1	1	1	1	1	1	1	1	0	0	0	0
U	E*	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1	1	1	1
Т		1																			

^{*}Omit for MM54C922/MM74C922

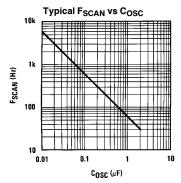
Typical Performance Characteristics



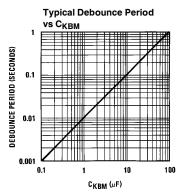
TL/F/6037-6



TL/F/6037-7



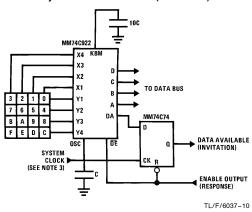
TL/F/6037-8



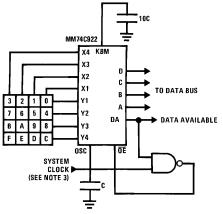
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Typical Applications

Synchronous Handshake (MM74C922)



Synchronous Data Entry Onto Bus (MM74C922)



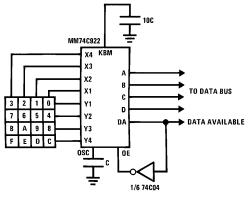
TL/F/6037-11

Outputs are enabled when valid entry is made and go into TRI-STATE when key is released.

Note 3: The keyboard may be synchronously scanned by omitting the capacitor at osc. and driving osc. directly if the system clock rate is lower than 10 kHz.

Typical Applications (Continued)

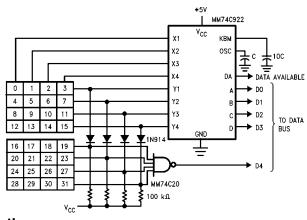
Asynchronous Data Entry Onto Bus (MM74C922)



TL/F/6037-12

Outputs are in TRI-STATE until key is pressed, then data is placed on bus. When key is released, outputs return to TRI-STATE.

Expansion to 32 Key Encoder (MM74C922)



Theory of Operation

The MM74C922/MM74C923 Keyboard Encoders implement all the logic necessary to interface a 16 or 20 SPST key switch matrix to a digital system. The encoder will convert a key switch closer to a 4(MM74C922) or 5(MM74C923) bit nibble. The designer can control both the keyboard scan rate and the key debounce period by altering the oscillator capacitor, C_{OSE}, and the key bounce mask capacitor, C_{MSK}. Thus, the MM74C922/MM74C923's performance can be optimized for many keyboards.

The keyboard encoders connect to a switch matrix that is 4 rows by 4 columns (MM74C922) or 5 rows by 4 columns (MM74C923). When no keys are depressed, the row inputs are pulled high by internal pull-ups and the column outputs sequentially output a logic "0". These outputs are open drain and are therefore low for 25% of the time and otherwise off. The column scan rate is controlled by the oscillator input, which consists of a Schmitt trigger oscillator, a 2-bit counter, and a 2-4-bit decoder.

When a key is depressed, key 0, for example, nothing will happen when the X1 input is off, since Y1 will remain high. When the X1 column is scanned, X1 goes low and Y1 will go low. This disables the counter and keeps X1 low. Y1 going

low also initiates the key bounce circuit timing and locks out the other Y inputs. The key code to be output is a combination of the frozen counter value and the decoded Y inputs. Once the key bounce circuit times out, the data is latched, and the Data Available (DAV) output goes high.

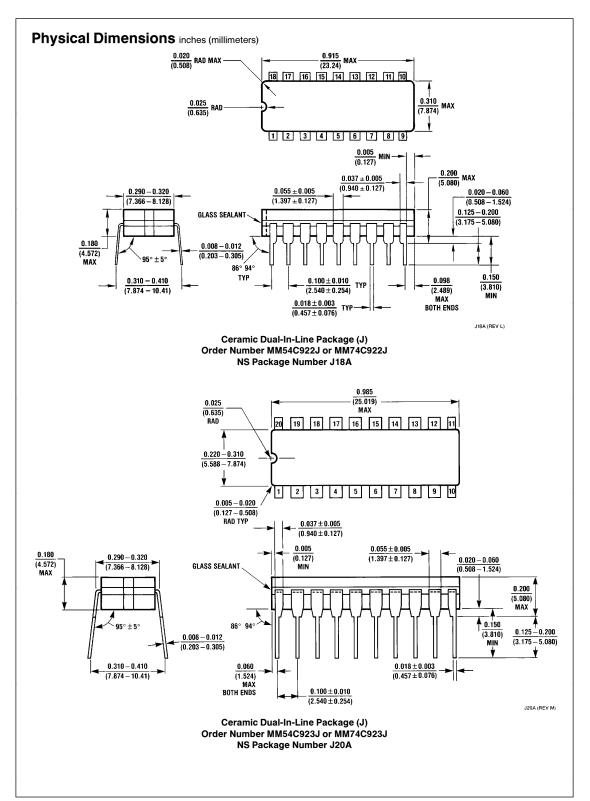
TL/F/6037-13

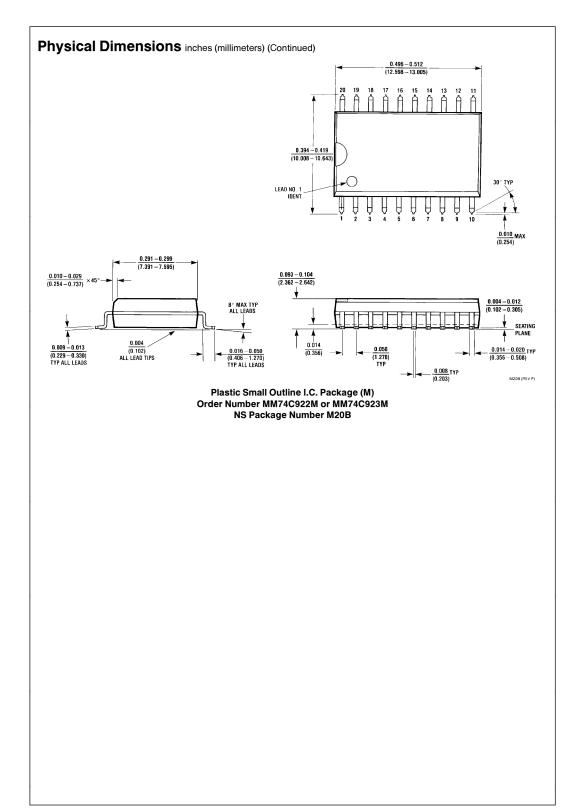
If, during the key closure the switch bounces, Y1 input will go high again, restarting the scan and resetting the key bounce circuitry. The key may bounce several times, but as soon as the switch stays low for a debounce period, the closure is assumed valid and the data is latched.

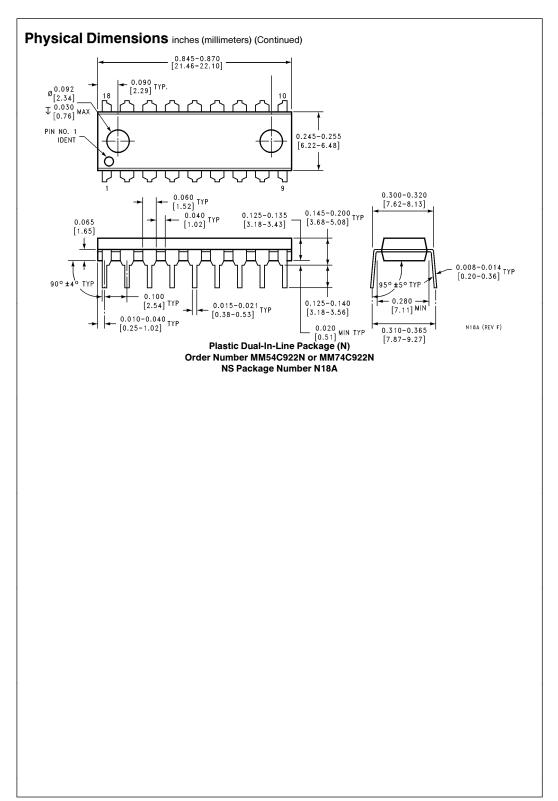
A key may also bounce when it is released. To ensure that the encoder does not recognize this bounce as another key closure, the debounce circuit must time out before another closure is recognized.

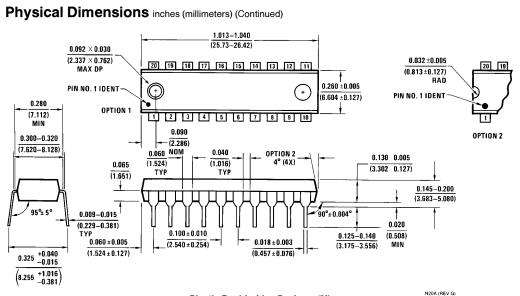
The two-key roll-over feature can be illustrated by assuming a key is depressed, and then a second key is depressed. Since all scanning has stopped, and all other Y inputs are disabled, the second key is not recognized until the first key is lifted and the key bounce circuitry has reset.

The output latches feed TRI-STATE, which is enabled when the Output Enable (\overline{OE}) input is taken low.









Plastic Dual-In-Line Package (N) Order Number MM54C923N or MM74C923N NS Package Number N20A

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